Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:

Metal

Overall Length:

6.500 inches

Overall Height:

0.750 inches

Overall Width:

0.750 inches

Mounting Facility Quantity:

2

Mounting Method:

Threaded hole

Features Provided:

Hermetically sealed case

Thread Size:

0.138 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

40000.0 reverse voltage, peak and 65.0 forward voltage, peak

Current Rating Per Characteristic:

25.00 amperes forward current, average preset

Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius ambient air

Test Data Document:

10001-2836190 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

Thread Series Designator:

Unc

Terminal Type And Quantity:

2 turret

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0